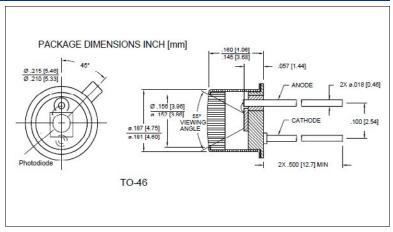




# GaN UV Photodiode SD012-UVB-011

#### Precision - Control - Results





#### **DESCRIPTION**

The **SD012-UVB-011** is a GaN **UVB** photodiode with a 0.076 mm<sup>2</sup> active area. Unlike most UV detectors it cuts off unwanted visible light from its detection spectrum (**220-320nm**), thereby eliminating the need for optical filter. Photodiode is assembled packaged in a hermetic TO-46 package

## RELIABILITY

This Luna high-reliability device is in principle able to meet military test requirements (Mil-STD-750, Mil-STD-883) after proper screening and group test.

Contact Luna for recommendations on specific test conditions and procedures.

#### **FEATURES**

- Schottky-Type Photodiode
- Photovoltaic Mode Operation
- Low Noise
- High Speed
- Visible Blindness

## **APPLICATIONS**

- UVB Detection and Monitoring
- Medical
- Military

## **ABSOLUTE MAXIMUM RATINGS**

SYMBOL	MIN		MAX	UNITS	T <sub>a</sub> = 23°C UNLESS NOTED OTHERWISE
Storage Temperature	-40	to	+85	°C	-
Operating Temperature	-30	to	+85	°C	-
Soldering Temperature	-	-	+260	°C	-
Forward Current	-	-	1.0	mA	-
Reverse Voltage	-	-	5.0	V	-

Information in this technical datasheet is believed to be correct and reliable. However, no responsibility is assumed for possible inaccuracies or omission. Specifications are subject to change without notice.

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Germany & Other Countries Laser Components GmbH Tel: +49 8142 2864 - 0 Fax: +49 8142 2864 - 11 info@lasercomponents.com www.lasercomponents.com



## **GaN UV Photodiode** SD012-UVB-011

## **Precision – Control – Results**

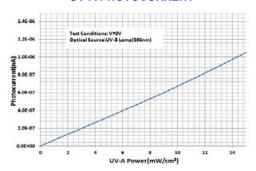
#### **OPTO-ELECTRICAL PARAMETERS**

T<sub>a</sub> = 23°C UNLESS NOTED OTHERWISE

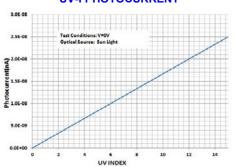
PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Dark Current	V <sub>R</sub> = 0.1V	-	0.1	100	pA
Shunt Resistance	V <sub>R</sub> = 10 mV	TBD	-	-	MΩ
Short Circuit Current	UVI=1.0	-	20	-	nA
Spectral Application Range	Spot Scan	220	-	370	Nm
Responsivity Peak	$\lambda$ = 300 nm V, V <sub>R</sub> = 0.V	-	0.1	-	A/W
Capacitance	$V_{bias} = 0V$ ; $f = 1 MHz$	-	10	-	pF
Noise Equivalent Power	λ= 300 nm	-	1.6	-	10 <sup>-</sup> 17W/Hz <sup>0.5</sup>

## **TYPICAL PERFORMANCE**

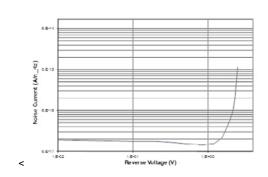
## **UV-A PHOTOCURRENT**



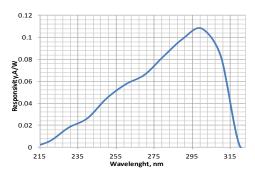
## **UV-I PHOTOCURRENT**



## **NOISE VS. BIAS**



#### **SPECTRAL RESPONSE**



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